ON Semiconductor

Is Now



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High Voltage Transistors

PNP Silicon

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage MPSA93 MPSA92	V _{CEO}	-200 -300	Vdc
Collector - Base Voltage MPSA93 MPSA92	V _{CBO}	-200 -300	Vdc
Emitter - Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current - Continuous	I _C	-500	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	–55 to +150	°C

THERMAL CHARACTERISTICS

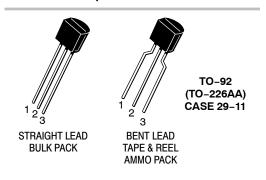
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	83.3	°C/W

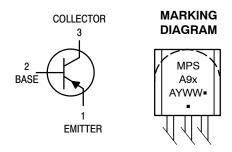
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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x = 2 or 3

A = Assembly Location

Y = Year WW = Work Week ■ Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS		1	1		I
Collector – Emitter Breakdown Voltage (Note 1) $(I_C = -1.0 \text{ mAdc}, I_B = 0)$	MPSA92 MPSA93	V _{(BR)CEO}	-300 -200	_ _	Vdc
Collector – Base Breakdown Voltage ($I_C = -100 \mu Adc, I_E = 0$)	MPSA92 MPSA93	V _{(BR)CBO}	-300 -200	- -	Vdc
Emitter – Base Breakdown Voltage $(I_E = -100 \mu Adc, I_C = 0)$		V _{(BR)EBO}	-5.0	-	Vdc
Collector Cutoff Current $(V_{CB} = -200 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -160 \text{ Vdc}, I_E = 0)$	MPSA92 MPSA93	I _{CBO}	_ _	-0.25 -0.25	μAdc
Emitter Cutoff Current $(V_{EB} = -3.0 \text{ Vdc}, I_{C} = 0)$		I _{EBO}	-	-0.1	μAdc
ON CHARACTERISTICS (Note 1)		•			
DC Current Gain $ (I_C = -1.0 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) $ $ (I_C = -10 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) $	All Types All Types	h _{FE}	25 40		-
($I_C = -30 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$)	MPSA92 MPSA93		25 25	_ _	
Collector – Emitter Saturation Voltage (I _C = -20 mAdc, I _B = -2.0 mAdc)	MPSA92 MPSA93	V _{CE(sat)}	- -	-0.5 -0.4	Vdc
Base–Emitter Saturation Voltage (I _C = -20 mAdc, I _B = -2.0 mAdc)		V _{BE(sat)}	-	-0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (I _C = –10 mAdc, V _{CE} = –20 Vdc, f = 100 MHz)		f _T	50	-	MHz
Collector-Base Capacitance (V _{CB} = -20 Vdc, I _E = 0, f = 1.0 MHz)	MPSA92 MPSA93	C _{cb}	- -	6.0 8.0	pF

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

ORDERING INFORMATION

Device	Package	Shipping [†]
MPSA92G	TO-92 (Pb-Free)	5000 Units / Box
MPSA92RL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSA92RLRA	TO-92	2000 / Tape & Reel
MPSA92RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSA92RLRMG	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA92RLRPG	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA92ZL1G	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA93G	TO-92 (Pb-Free)	5000 Units / Box
MPSA93RLRMG	TO-92 (Pb-Free)	2000 / Ammo Pack

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

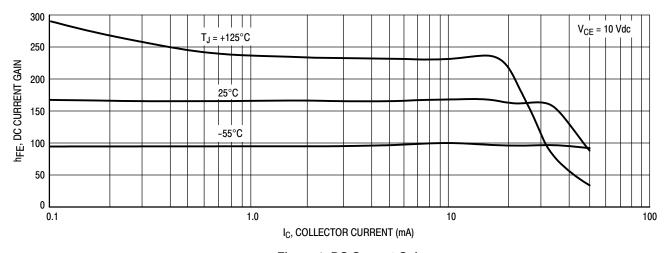
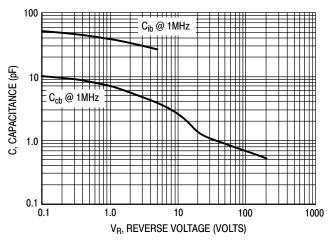


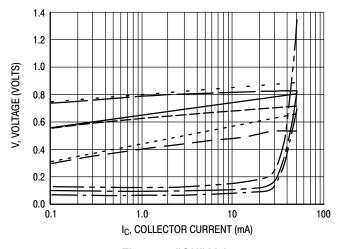
Figure 1. DC Current Gain



150 f_{T} , CURRENT-GAIN — BANDWIDTH (MHz) 130 110 90 70 50 $T_J = 25^{\circ}C$ V_{CE} = 20 Vdc 30 F = 20 MHz 10 11 13 15 17 19 IC, COLLECTOR CURRENT (mA)

Figure 2. Capacitance

Figure 3. Current-Gain - Bandwidth



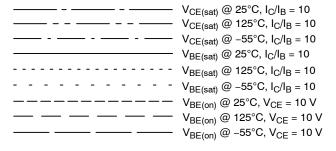


Figure 4. "ON" Voltages

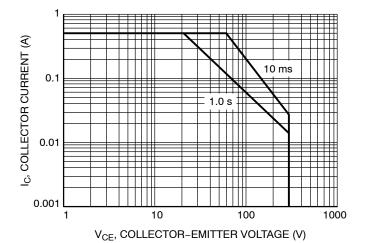
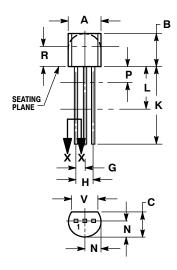


Figure 5. Safe Operating Area

PACKAGE DIMENSIONS

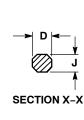
TO-92 (TO-226) CASE 029-11 **ISSUE AM**



STRAIGHT LEAD **BULK PACK**



BENT LEAD TAPE & REEL AMMO PACK



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R
- IS UNCONTROLLED.
 LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
v	0.135		3 //3	

STYLE 14:

- PIN 1. EMITTER
 - 2 COLLECTOR
 - BASE 3.

NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
P	1.50	4.00	
R	2.93		
٧	3.43		

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